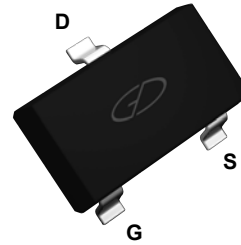
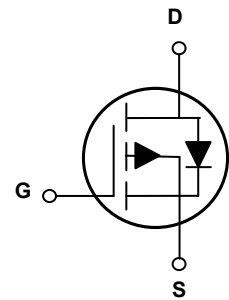


Main Product Characteristics

$V_{(BR)DSS}$	-30V
$R_{DS(ON)}$	85m Ω (Max.)
I_D	-3A



SOT-23



Schematic Diagram

Features and Benefits

- Advanced MOSFET process technology
- Ideal for high efficiency switched mode power supplies
- Low on-resistance with low gate charge
- Fast switching and reverse body recovery



Description

The SSF3365 utilizes the latest techniques to achieve high cell density and low on-resistance. These features make this device extremely efficient and reliable for use in high efficiency switch mode power supplies and a wide variety of other applications.

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Max.	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-to-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current, @ Steady-State ($T_A=25^\circ\text{C}$) ¹	I_D	-3.0	A
Continuous Drain Current, @ Steady-State ($T_A=70^\circ\text{C}$)		-1.8	A
Pulsed Drain Current ²	I_{DM}	-12	A
Power Dissipation ($T_A=25^\circ\text{C}$)	P_D	1.2	W
Linear Derating Factor ($T_A=25^\circ\text{C}$)		9.6	mW/ $^\circ\text{C}$
Junction-to-Ambient (PCB Mounted, Steady-State) ³	$R_{\theta JA}$	100	$^\circ\text{C/W}$
Operating Junction and Storage Temperature Range	T_J/T_{STG}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics (T_J=25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
On / Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30	-	-	V
BV _{DSS} Temperature Coefficient	ΔBV _{DSS} /ΔT _J	Reference to 25°C, I _D =-1mA	-	-0.03	-	V/°C
Drain-Source Leakage Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V, T _J =25°C	-	-	-1	uA
		V _{DS} =-24V, V _{GS} =0V, T _J =125°C	-	-	-10	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} =-10V, I _D =-3A	-	59	85	mΩ
		V _{GS} =-4.5V, I _D =-2.5A	-	89	107	
Gate Threshold Voltage	V _{GS(th)}	V _{GS} =V _{DS} , I _D =-250uA	-1.0	-1.6	-2.9	V
V _{GS(th)} Temperature Coefficient	ΔV _{GS(th)}		-	4	-	mV/°C
Forward Transconductance	g _{fs}	V _{DS} =-10V, I _D =-3A	-	3.7	-	S
Dynamic and Switching Characteristics						
Total Gate Charge ^{2,3}	Q _g	V _{DS} =-30V, V _{GS} =-4.5V, I _D =-2A	-	5	8	nC
Gate-Source Charge ^{2,3}	Q _{gs}		-	1.4	3	
Gate-Drain Charge ^{2,3}	Q _{gd}		-	1.7	4	
Turn-On Delay Time ^{2,3}	t _{d(on)}	V _{DD} =-30V, V _{GS} =-10V, R _G =6Ω, I _D =-1A	-	3.4	6	nS
Rise Time ^{2,3}	t _r		-	10.8	21	
Turn-Off Delay Time ^{2,3}	t _{d(off)}		-	26.9	51	
Fall Time ^{2,3}	t _f		-	6.9	13	
Input Capacitance	C _{iss}	V _{DS} =-30V, V _{GS} =0V, F=1MHz	-	420	810	pF
Output Capacitance	C _{oss}		-	50	80	
Reverse Transfer Capacitance	C _{rss}		-	35	60	
Source-Drain Ratings and Characteristics						
Continuous Source Current	I _S	V _G =V _D =0V, Force Current	-	-	-3	A
Pulsed Source Current	I _{SM}		-	-	-6	A
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =1A, T _J =25°C	-	-	-1.2	V

Notes:

1. Repetitive Rating: Pulsed width limited by maximum junction temperature.
2. The data tested by pulsed, pulse width ≤ 300uS, duty cycle ≤ 2%.
3. Essentially independent of operating temperature.

Typical Electrical and Thermal Characteristics

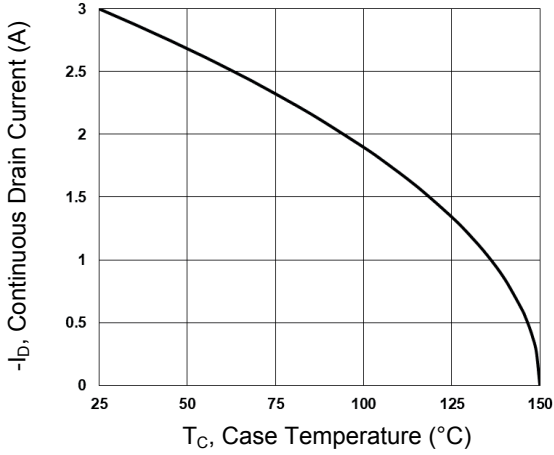


Figure 1. Continuous Drain Current vs. T_C

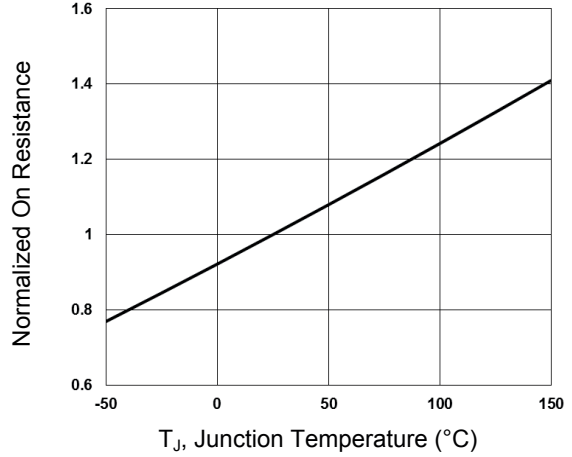


Figure 2. Normalized $R_{DS(ON)}$ vs. T_J

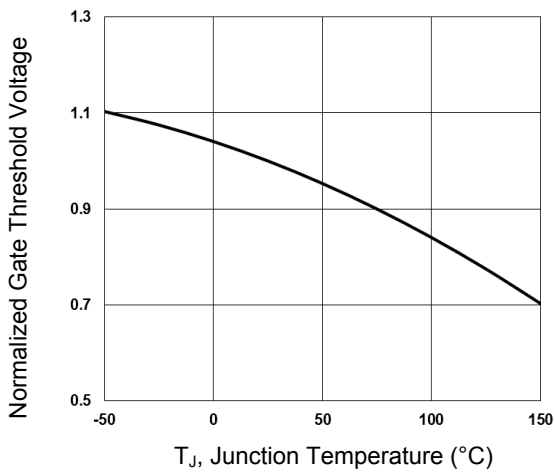


Figure 3. Normalized V_{th} vs. T_J

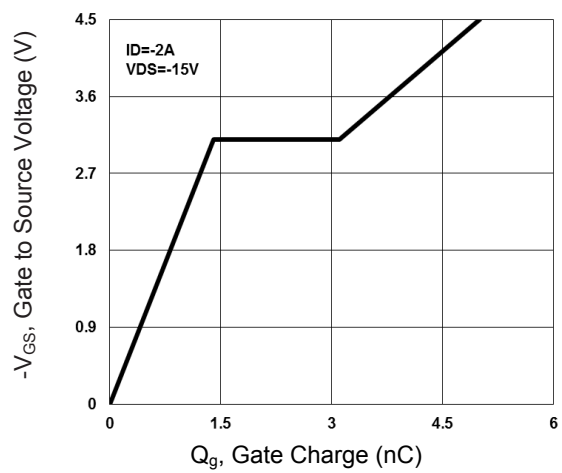


Figure 4. Gate Charge Waveform

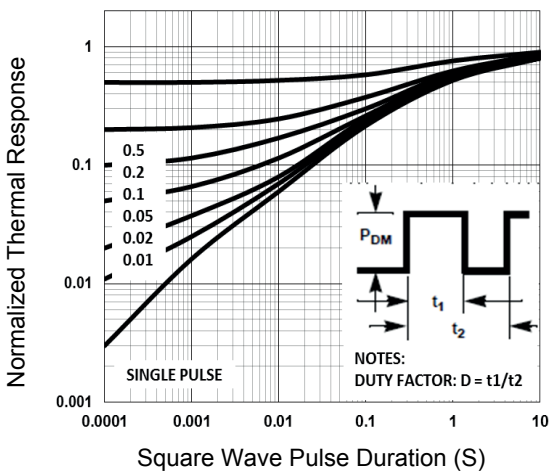


Figure 5. Normalized Transient Impedance

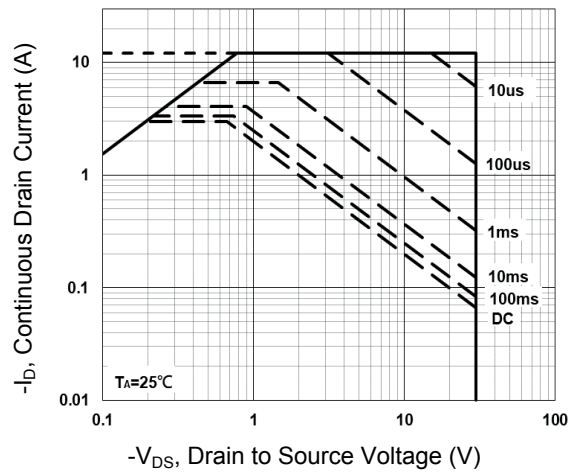
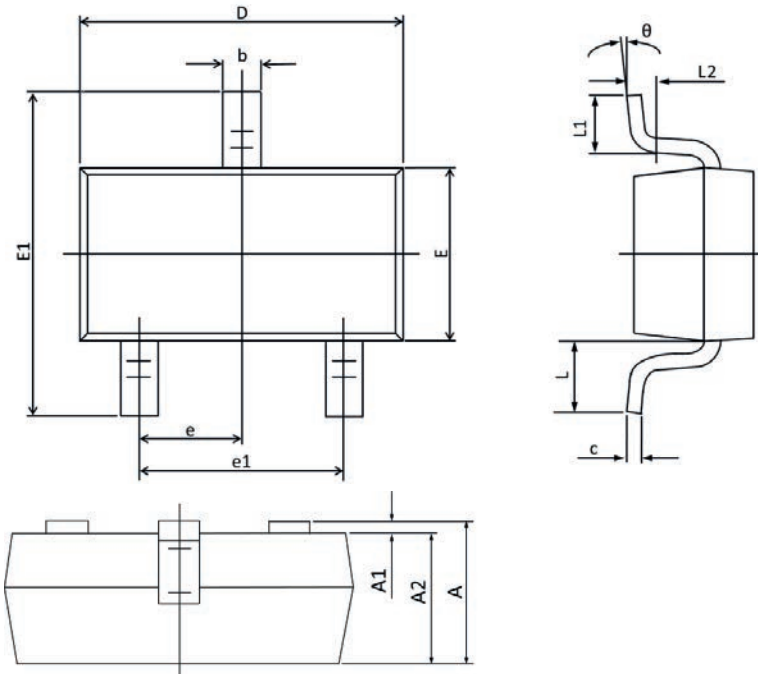


Figure 6. Maximum Safe Operation Area

Package Outline Dimensions (SOT-23)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.95 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.55 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
L2	0.25 TYP.		0.01 TYP.	
θ	0°	8°	0°	8°

Order Information

Device	Package	Marking	Carrier	Quantity
SSF3365	SOT-23	3365	Tape & Reel	3,000 pcs / Reel